

				T
L	Hits	Search Text	DB	Time stamp
Number				2000 100 100
17	2	("3873361" "4353935").PN.	USPAT	2003/06/26
- '				08:58
18	18	4448800.URPN.	USPAT	2003/06/26
10				08:58
45	7	("4013484" "4144101" "4244752"	USPAT	2003/06/26
43	, i	"4280272" "4306916" "4315781"		09:15
		"4435896").PN.		
46	34	4558508.URPN.	USPAT	2003/06/26
40]	1000001011111		09:19
69	12	("3728161" "3773566" "4074301"	USPAT	2003/06/26
69	12	"4140547" "4149307" "4294002"		09:29
1		"4315781" "4329186" "4398964"		
		"4426766" "4441941" "4485550").PN.		
	13		USPAT	2003/06/26
70	13	46/9303.0KEN.		09:31
	3259	metal with (dioxide or insulating or	USPAT;	2003/06/25
-	3239	oxide) with (implant\$5 or doping)	US-PGPUB	19:17
	501	(metal with (dioxide or insulating or	USPAT;	2003/06/25
-	501	oxide) with (implant\$5 or doping)) with	US-PGPUB	19:15
		(mask\$3)		
		(mask\$3) ((metal with (dioxide or insulating or	USPAT;	2003/06/25
-	38	oxide) with (implant\$5 or doping)) with	US-PGPUB	19:18
		(mask\$3)) and schottky		ļ
	4.77	((metal with (dioxide or insulating or	USPAT;	2003/06/25
-	477	oxide) with (implant\$5 or doping)) with	US-PGPUB	19:15
ļ		(mask\$3)) and semiconductor		
Ì		((mask\$3)) and semiconductor (((metal with (dioxide or insulating or	USPAT;	2003/06/25
-	439	(((metal with (dioxide of insurating of	US-PGPUB	19:15
1		oxide) with (implant\$5 or doping)) with (mask\$3)) and semiconductor) not ((metal	05 10102	
		(mask\$3)) and semiconductor, not ((metal		
		with (dioxide or insulating or oxide)		
ļ		with (implant\$5 or doping)) with	1	
		(mask\$3)) and schottky)	USPAT;	2003/06/25
-	26361	metal with (mask\$3)	US-PGPUB	19:18
		1.42\\	USPAT;	2003/06/25
-	1182	(metal with (mask\$3)) and schottky	US-PGPUB	19:18
			103-FGEOD	1 = 2 - 1